# Characterization of VUV-sensitive SiPMs for nEXO

### Michael Wagenpfeil (for the nEXO collaboration)

# **Physic beyond Standard Model?**

- The neutrinoless double beta decay opens window to physics beyond SM
- Are neutrinos Majorana particles?



- Current  $0\nu\beta\beta$  searches are sensitive to a half life of about  $10^{26}$  years
- nEXO plans to increase sensitivity by two orders of magnitude

# The nEXO detector

- Time-projection-chamber (TPC) filled with ~ 5 tons of liquid Xenon (LXe) – enriched to 90% in <sup>136</sup>Xe
- Cylindric barrel with a diameter and height of 1.3 m
- Detector set up in underground lab to shield from cosmic rays (likely SNOLAB, 6000 mwe.)
- Signal detection via charge readout tiles (end cap) and VUV-sensitive SiPMs (inner wall)
- Cathode set to -60 keV to produce axial drift field
- Extensive radiopurity screening to constrain BG
- Homogeneous detector & multi-parameter analysis



# **Light detection**

 nEXO sensitivity depends on light collection efficiency and photo detection efficiency

# SiPM characterization test setups

ECAP, Erlangen (Dark noise, PDE, collab. with U.Münster for VUV reflectance)
IHEP, Beijing (HV behaviour, VUV reflectance)
TRIUMF, Vancouver (Dark noise, PDE)
UA, Alabama (VUV reflectance)
Stanford (PDE, SiPM tiles)
UMass (PDE, LXe)

Readout

Preamp

PMT

SiPM

Xe-cell

Cooling

Light source

- Inside wall covered with 4 m<sup>2</sup> of VUV-sensitive SiPMs
- Detection of 178 nm scintillation light in the LXe
- Goal: 1% energy resolution at Q-vlaue (2458 keV)
- Strong requirements on SiPM parameters



Parameters	Value
Photo detection efficiency at 175-178 nm (without AR coating measured in gas/vacuum)	>15%
Radiopurity: Contribution of photo-detectors to the overall background	<1%
Dark noise rate	<50 Hz/mm <sup>2</sup>
Probability for correlated avalanches per parent avalance	<20%
Active area per single photo-detector	>1cm <sup>2</sup>
Capacitance	<50pF/mm <sup>2</sup>
Pulse width (after electronics shaping)	<100 ns

# Various SiPMs

Hamamatsu VUV3, VUV4
FBK NUV 2016 LF & STD





# Measuring procedure @ ECAP

- Record SiPM pulses under dark & light conditions at -100°C
- Fit waveforms with pulse template
- Account for afterpulsing and crosstalk
- Use amplitude, timestamp, rise/fall time

# Afterpulsing

- Delayed avalanches correlated to the primary pulse
- Important nuisance charge contribution

# PDE

- Efficiency to detect single photons
- Angle-, wavelength- and bias voltage-dependent

# **Energy resolution**

- Depends on PDE and photon transport efficiency
- Example performance in the case of PTE = 0.2

#### for further analysis







# **VUV** reflectance

- Knowing VUV reflectance of TPC surfaces important for photo collection efficiency
   Measured in collaboration with the Institut
- Measured in collaboration with the Institut für Kernphysik, University of Münster



- Measurements accomplished in LXe at -90°C and for 178 nm photons
- Reflectance calculated as ratio between reflectance and zero-reference intensity







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#### PM2018 - 14th Pisa Meeting on Advanced Detectors 27 May to 02 June 2018 - La Biodola, Isola d'Elba (Italy)